## NSN 5961-01-159-3169

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-159-3169 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.980 inches **Overall Diameter:** 0.450 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage and 48.0 nonrepetitive peak reverse voltage and 28.0 reverse voltage, total rms **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute and 500.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No